

Ultra-Low Capacitance ESD Protection Diode

1. Features

- Ultra Low Capacitance: 0.35pF(typ.)
- Reverse Working Voltage: 5V
- IEC 61000-4-2 (ESD Air): ± 20 kV
IEC 61000-4-2 (ESD Contact): ± 20 kV
IEC 61000-4-5 (Lightning 8/20 μ s): 4.5A

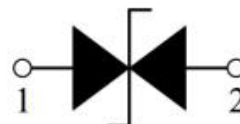
2. Pin Description



3. Applications

- Smart Phone and Tablet PC
- TV and Set Top Box
- Wearable Devices
- PDA

4. Schematic Diagram



5. Order Information

Type	Package	Size (mm)	Delivery Form	Delivery Quantity
SEU0501P1	DFN1006	1.00x0.60x0.37	7" T&R	10,000

6. Limiting Values($T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{ESD}	Electrostatic Discharge Voltage	IEC 61000-4-2; Contact Discharge	-	± 20	kV
		IEC 61000-4-2; Air Discharge	-	± 20	kV
P_{PP}	Peak Pulse Power	$t_P = 8/20\ \mu\text{s}$	-	100	W
I_{PPM}	Rated Peak Pulse Current	$t_P = 8/20\ \mu\text{s}$	-	4.5	A
T_A	Operating Temperature Range	-	-55	125	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-	-55	150	$^\circ\text{C}$

7. Electrical Characteristics ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Conditions	Min	Typ.	Max	Unit
V_{RWM}	Reverse Working Voltage	$T_A = 25\text{ }^\circ\text{C}$	-	-	5.0	V
V_{BR}	Breakdown Voltage	$I_R = 1\text{ mA}; T_A = 25\text{ }^\circ\text{C}$	6.0	8.5	9.5	V
I_R	Reverse Leakage Current	$V_{RWM} = 5\text{ V}; T_A = 25\text{ }^\circ\text{C}$	-	-	0.1	μA
V_C	Clamping Voltage	$I_{PP} = 1\text{ A}, t_p = 8/20\mu\text{s}$	-	-	11	V
		$I_{PP} = 4.5\text{ A}, t_p = 8/20\mu\text{s}$	-	-	22	V
C_J	Junction Capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$	-	0.35	0.45	pF

8. Typical Characteristics

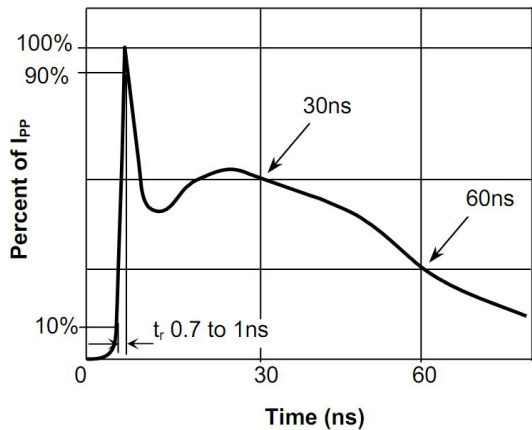


Fig.1 Pulse Waveform-ESD(IEC61000-4-2)

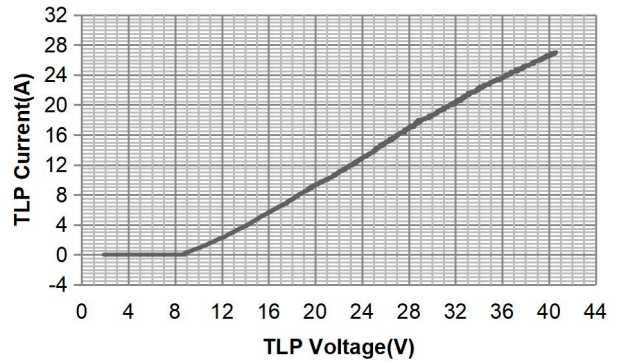


Fig.2 Transmission Line Pulse (TLP)

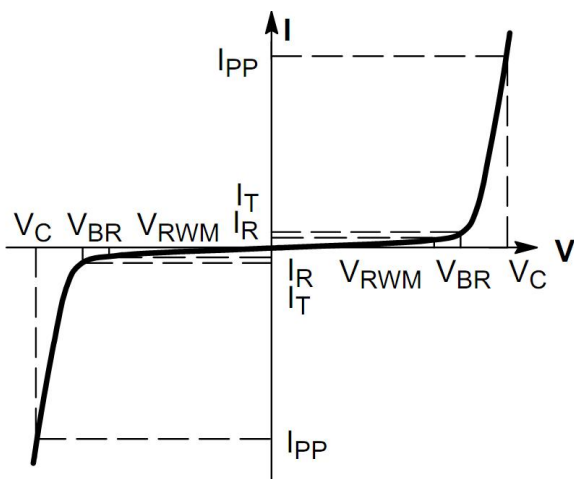


Fig.3 V-I Characteristics for Bidirectional Diode

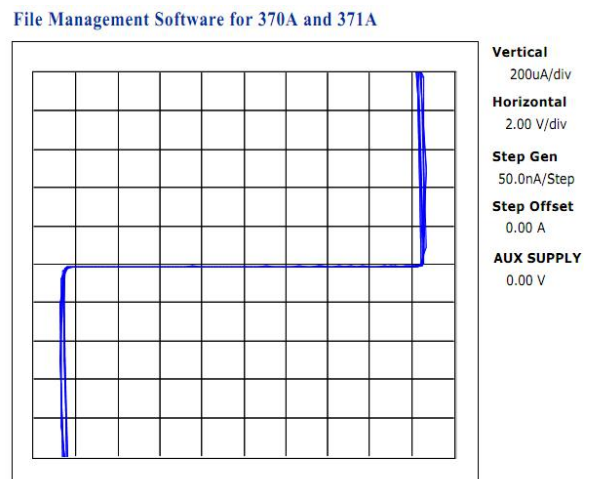
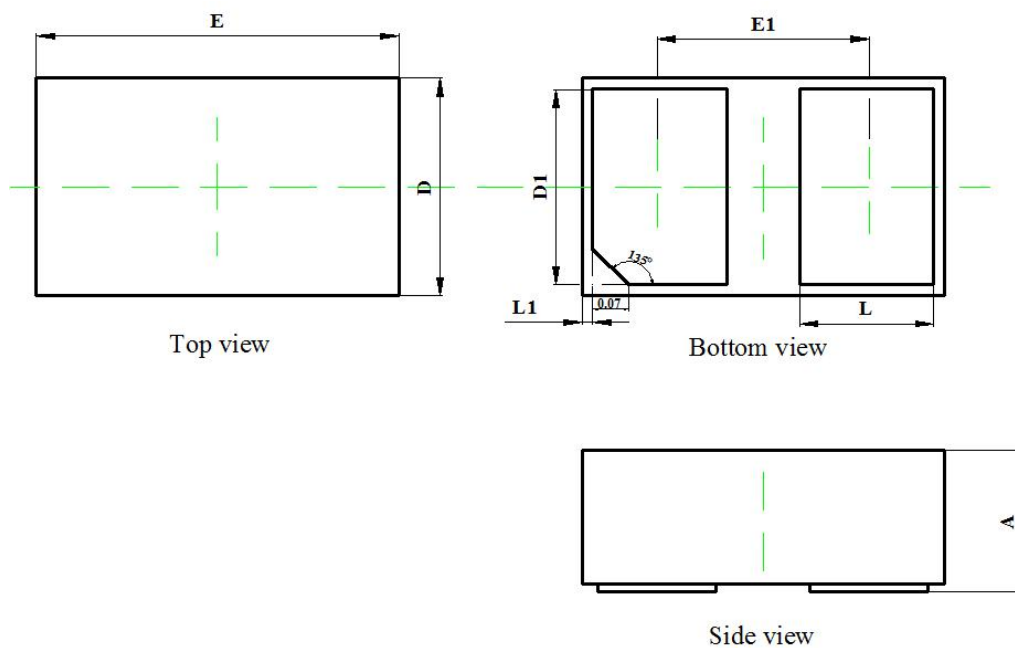
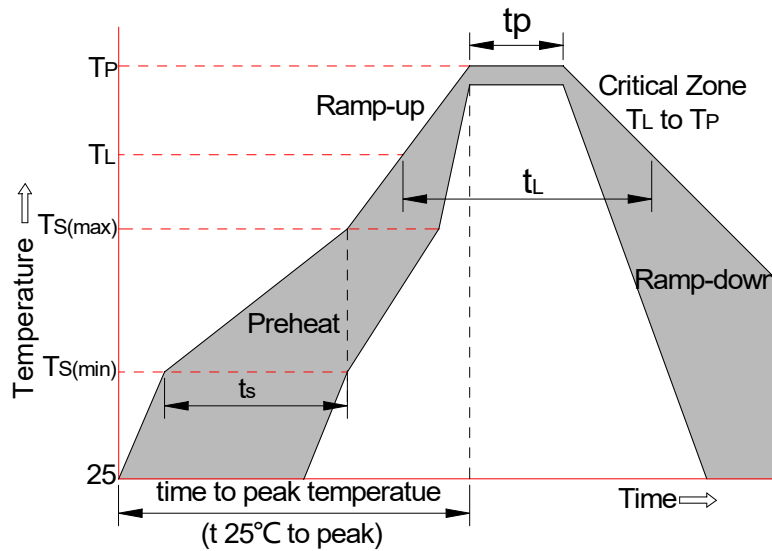


Fig.4 IV Curve

9. Package Dimension
DFN1006 Package Outline


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.320	0.420	0.013	0.017
D	0.550	0.650	0.022	0.026
E	0.950	1.050	0.037	0.041
D1	0.450	0.550	0.018	0.022
E1	0.550	0.650	0.022	0.026
L	0.280	0.380	0.011	0.015
L1	0.000	0.100	0.000	0.004

10. Soldering Parameters


Reflow Condition		Pb-Free Assembly
Pre-heat	-Temperature Min ($T_{s(min)}$)	+150°C
	-Temperature Max($T_{s(max)}$)	+200°C
	-Time (Min to Max) (t_s)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3°C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L)(Liquid us)	+217°C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
xTime 25°C to Peak Temp (T_p)		8 min. Max
Do not exceed		+260°C